

TC7MH574FK

Octal D-Type Flip-Flop with 3-State Output

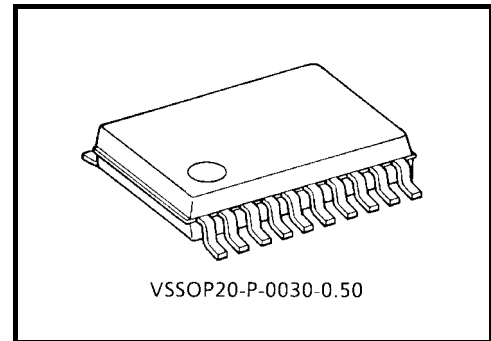
The TC7MH574FK is an advanced high speed CMOS octal flip-flop with 3-state output fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ($\overline{OE}$).

When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

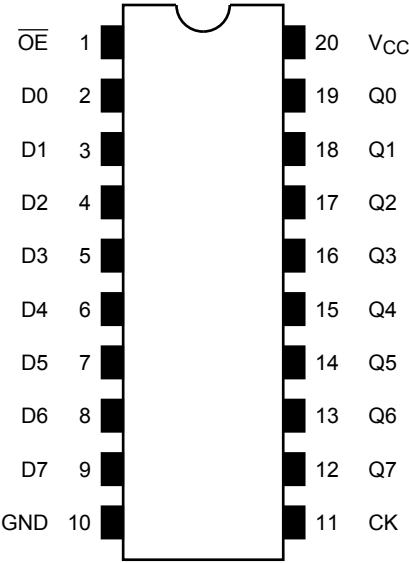


Weight: 0.03 g (typ.)

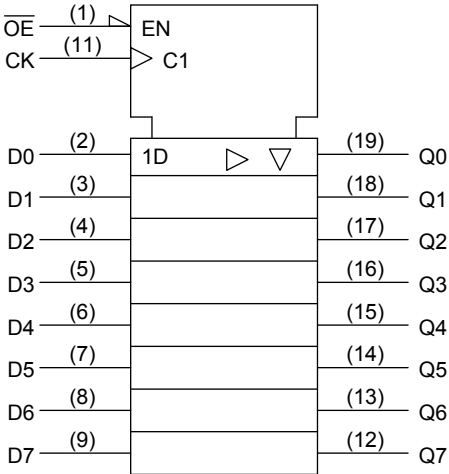
Features

- High speed: $f_{\max} = 180 \text{ MHz}$ (typ.) ($V_{CC} = 5 \text{ V}$)
- Low power dissipation: $I_{CC} = 4 \text{ }\mu\text{A}$ (max) ($T_a = 25^\circ\text{C}$)
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC}(\text{opr}) = 2 \sim 5.5 \text{ V}$
- Low noise: $V_{OLP} = 1.0 \text{ V}$ (max)
- Pin and function compatible with 74ALS574

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

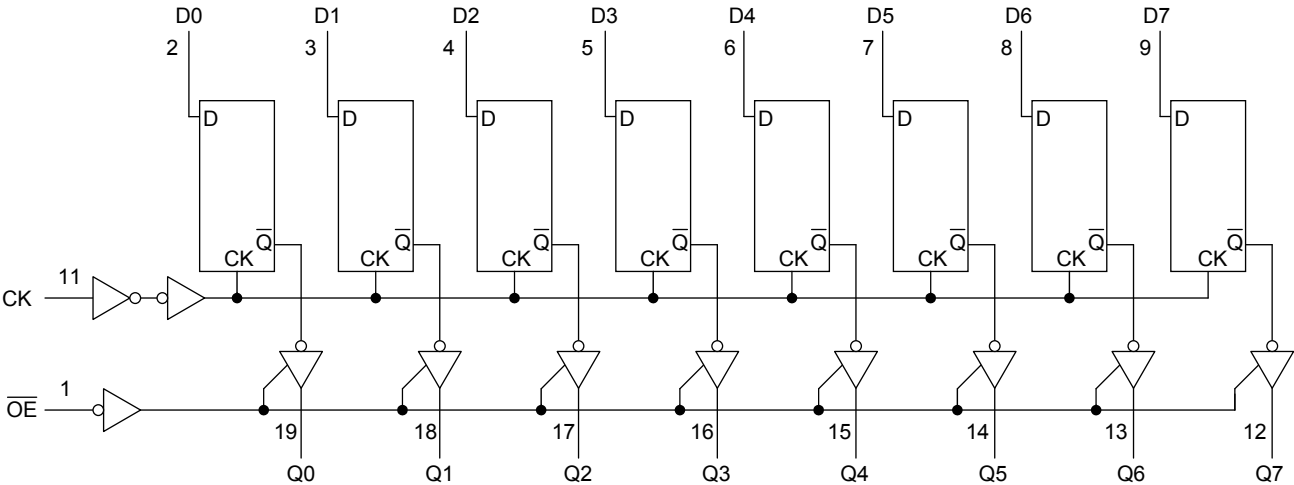
Inputs			Outputs
OE	CK	D	
H	X	X	Z
L		X	Q _n
L		L	L
L		H	H

X: Don't care

Z: High impedance

Q_n: No change

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	$-0.5 \sim 7.0$	V
DC input voltage	V_{IN}	$-0.5 \sim 7.0$	V
DC output voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	$-65 \sim 150$	$^{\circ}\text{C}$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~ V_{CC}	V
Operating temperature	T_{opr}	$-40 \sim 85$	$^{\circ}\text{C}$
Input rise and fall time	dt/dv	0~100 ($V_{CC} = 3.3 \pm 0.3 \text{ V}$)	ns/V
		0~20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C				Ta = -40~85°C		Unit				
					V _{CC} (V)	Min	Typ.	Max	Min	Max					
Input voltage	High level	V _{IH}	—		2.0	1.50	—	—	1.50	—	V				
					3.0~5.5	V _{CC} × 0.7	—	—	V _{CC} × 0.7	—					
	Low level	V _{IL}	—		2.0	—	—	0.50	—	0.50					
					3.0~5.5	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3					
Output voltage	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V				
					3.0	2.9	3.0	—	2.9	—					
					4.5	4.4	4.5	—	4.4	—					
				I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—					
					I _{OH} = -8 mA	4.5	3.94	—	—	3.80		—			
	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1					
					3.0	—	0	0.1	—	0.1					
					4.5	—	0	0.1	—	0.1					
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44					
					I _{OL} = 8 mA	4.5	—	—	0.36	—		0.44			
				3-state output off-state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND	5.5	—	—		±0.25	—	±2.50	μA
				Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND	0~5.5	—	—		±0.1	—	±1.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	4.0	—	40.0	μA					

Timing Requirements (Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	Typ.	Limit	Limit	Limit	
Minimum pulse width (CK)	t _w (H) t _w (L)	—	3.3 ± 0.3	—	5.0	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	5.0	
Minimum set-up time	t _s	—	3.3 ± 0.3	—	3.5	3.5	3.5	ns
			5.0 ± 0.5	—	3.5	3.5	3.5	
Minimum hold time	t _h	—	3.3 ± 0.3	—	1.5	1.5	1.5	ns
			5.0 ± 0.5	—	1.5	1.5	1.5	

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.5	13.2	1.0	15.5	ns
				50	—	11.0	16.7	1.0	19.0	
			5.0 ± 0.5	15	—	5.6	8.6	1.0	10.0	
				50	—	7.1	10.6	1.0	12.0	
3-state output enable time	t_{pZL} t_{pZH}	$R_L = 1 \text{ k}\Omega$	3.3 ± 0.3	15	—	8.2	12.8	1.0	15.0	ns
				50	—	10.7	16.3	1.0	18.5	
			5.0 ± 0.5	15	—	5.9	9.0	1.0	10.5	
				50	—	7.4	11.0	1.0	12.5	
3-state output disable time	t_{pLZ} t_{pHZ}	$R_L = 1 \text{ k}\Omega$	3.3 ± 0.3	50	—	11.0	15.0	1.0	17.0	ns
			5.0 ± 0.5	50	—	7.1	10.1	1.0	11.5	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	80	125	—	65	—	MHz
				50	50	75	—	45	—	
			5.0 ± 0.5	15	130	180	—	110	—	
				50	85	115	—	75	—	
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C _{IN}	—	—	—	—	4	10	—	10	pF
Output capacitance	C _{OUT}	—	—	—	—	6	—	—	—	pF
Power dissipation capacitance	C _{PD}	(Note 2)	—	—	—	28	—	—	—	pF

Note 1: This parameter is guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per F/F)}$$

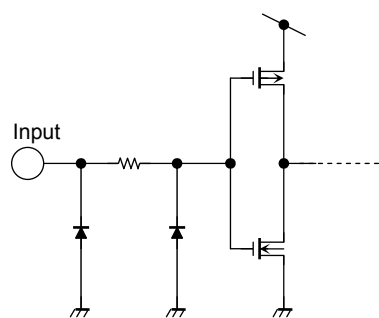
And the total C_{PD} when n pcs of latch operate can be gained by the following equation:

$$C_{PD(total)} = 20 + 8 \cdot n$$

Noise Characteristics (Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V _{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	V
Minimum high level dynamic input voltage V _{IH}	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage V _{IL}	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

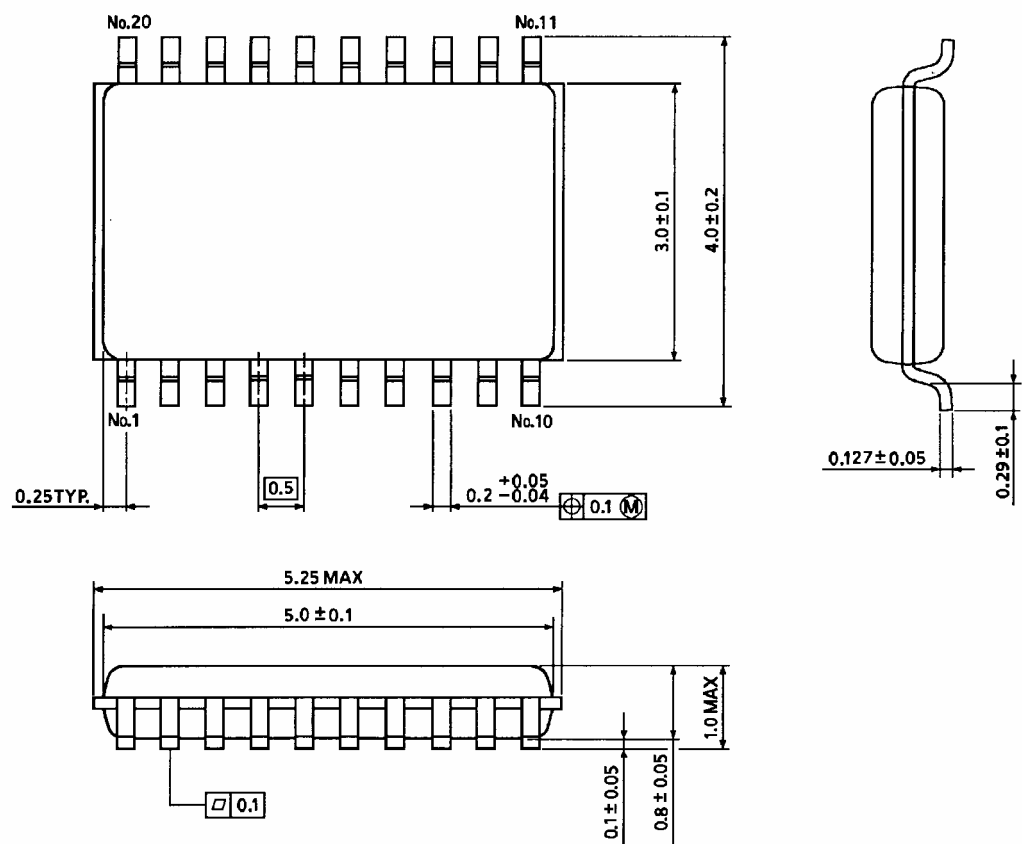
Input Equivalent Circuit



Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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